DERWENT-ACC-NO: 1988-255069

DERWENT-WEEK: 198836

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TITLE: Solder ball for semiconductor chip - has height

increased so that

stress gaused by difference in thermal expansion between

chip and substrate is

minimised

PATENT-ASSIGNEE: ANONYMOUS[ANON]

PRIORITY-DATA: 1988RD-0291011 (June 20, 1988)

PATENT-FAMILY:

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MAIN-IPC

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INT-CL (IPC): H01L000/01

ABSTRACTED-PUB-NO: RD 291011A

BASIC-ABSTRACT: A substrate has a solder dam (F) over a substrate conductor

The chip pad site substrate conductor (G) is then tinned with a low

temperature solder alloy (A) to form the base for a chip pad solder column.

Next, a high melt solder alloy (B) is evaporated or electroplated on top of the

tinning solder (A) to form a solder colum (AB). Finally, another layer of low

melt solder alloy (A) is evaporated or electroplated on top of the solder

column (AB) to form solder column (ABA').

The composite structure is reflowed at chip joining time with a temperature

appropriate for low melting solder (A) but below that of the high melt

temperature of solder (B). The second alloy (B) retains is geometry and,

therefore, the height of the column is retained. Also, by virtue of the lower

joining temperature used the chip's solder ball (D), which is also composed of the high melt solder alloy, retains its geometry.

CHOSEN-DRAWING: Dwg.1/1

TITLE-TERMS:

SOLDER BALL SEMICONDUCTOR CHIP HEIGHT INCREASE SO STRESS CAUSE DIFFER THERMAL EXPAND CHIP SUBSTRATE MINIMISE

DERWENT-CLASS: U11

EPI-CODES: U11-D03B3;

SECONDARY-ACC-NO:

Non-CPI Secondary Accession Numbers: N1988-193649

